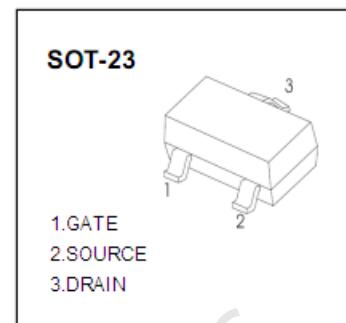
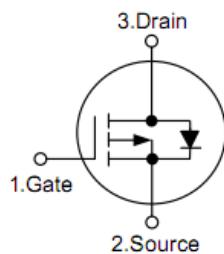


特点/Features :

- 1、开关速度快；
- 2、导通电阻低；

用途/Applications :

用于一般开关和低压电源电路。


印章/MARKING:A1SHB
极限参数/Absolute maximum ratings(Ta=25°C)

参数/Parameter	符号/ Symbol	数值/Value	单位/Unit
漏极-源极电压/Drain-Source Voltage	V_{DS}	-20	V
栅极-源极电压/Gate-Source Voltage	V_{GS}	± 8	V
漏极电流 (持续) /Continuous Drain Current	I_D	-2.3	A
漏极电流 (脉冲) /Pulsed Drain Current	I_{DM}	-10	A
耗散功率/Power Dissipation	P_D	0.35	W
热阻/ Thermal Resistance Junction to Ambient	$R_{\theta JA}$	350	°C/mW
结温/Junction Temperature	T_j	150	°C
储存温度/Storage Temperature	T_{stg}	-55~150	°C

电性能参数/Electrical characteristics (Ta=25°C)

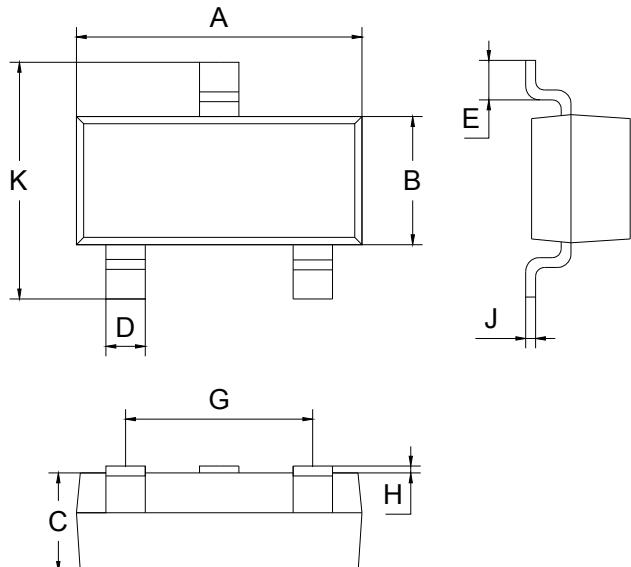
参数	符号	测试条件	最小值	典型值	最大值	单位
静态/Static Characteristics						
源极-漏极击穿电压	V _{BR(DSS)}	V _{GS} =0V, I _D =-250 μA	-20			V
栅极开启电压	V _{GS(th)}	I _D =-250 μA, V _{GS} =V _{DS}	0.4		-1	V
栅极漏电流	I _{GSS}	V _{GS} =±8V, V _{DS} =0V			±100	nA
零栅压漏极电流	I _{DSS}	V _{GS} =0V, V _{DS} =-20V			-1	μA
漏极源极导通电阻	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-2.8A		0.090	0.112	Ω
		V _{GS} =-2.5V, I _D =-2A		0.110	0.142	
正向跨导	g _{fs}	V _{DS} =-5V, I _D =-2.8A		6.5		S
动态/Dynamic Characteristics						
输入电容	C _{iss}	V _{DS} =-10V, V _{GS} =0V, f=1MHz		405		pF
输出电容	C _{oss}			75		
反向传输电容	C _{rss}			55		
开关参数/Switching Characteristics						
总栅极充电电荷	Q _G	V _{DS} =-6V, V _{GS} =-4.5V, I _D =-2.8A		5.4	10	nC
栅极-源极充电电荷	Q _{GS}			0.8		nC
栅极-漏极充电电荷	Q _{GD}			1.1		nC
开启延时	t _{D(on)}	V _{DD} =-10V, I _D =-1A, V _{GEN} =-4.5V, R _G =1 Ω, R _L =10 Ω		11	20	ns
上升时间	t _R			35	60	ns
关闭延时	t _{D(off)}			30	50	
下降延时	T _f			10	20	
漏极-源极二极管参数/Drain-source Body Diode Characteristics						
源极-漏极二极管电流	I _S	T _c =25°C			-1.3	A
二极管正向脉冲电流	I _{SM}				-10	A
二极管正向压降	V _{SD}	I _S =-0.7A		-0.8	-1.2	V

注：① 脉冲测试脉冲宽度≤300μS, 占空比≤2%;

封装尺寸/PACKAGE OUTLINE

Plastic surface mounted package

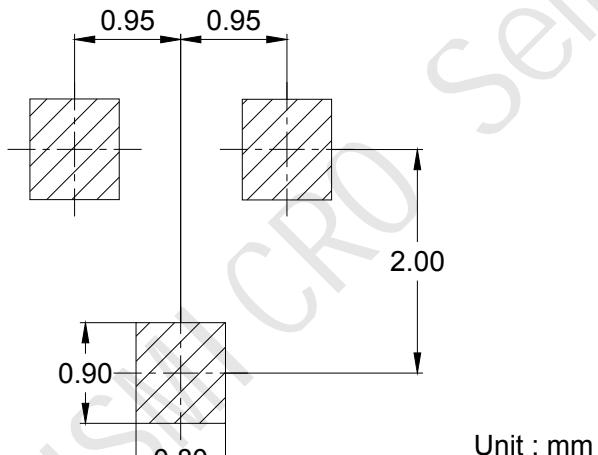
SOT-23



SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	0.9	1.1
D	0.3	0.5
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.05	0.15
K	2.20	2.60

All Dimensions in mm

SOLDERING FOOTPRINT



Unit : mm